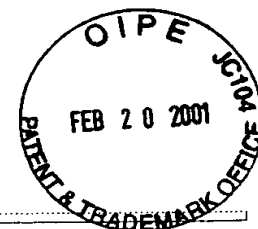


PATENT ABSTRACTS OF JAPAN



(11)Publication number : 10-149832
(43)Date of publication of application : 02.06.1998

(51)Int.Cl. H01M 4/58
H01M 4/02
H01M 10/40

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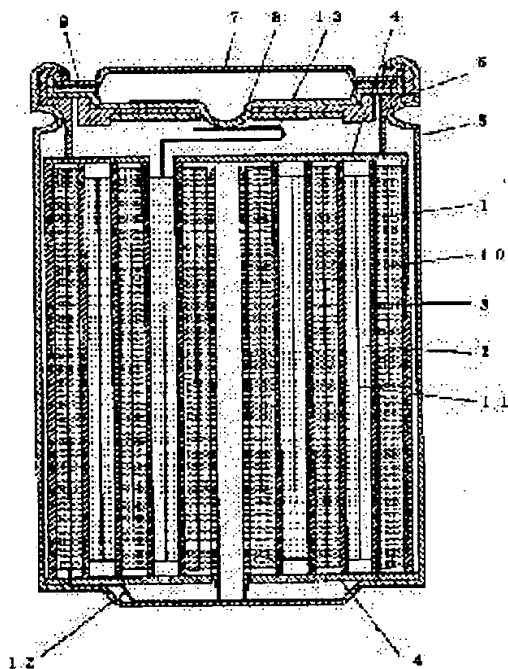
(54) NONAQUEOUS ELECTROLYTE SECONDARY BATTERY

(57)Abstract:

PROBLEM TO BE SOLVED: To concurrently realize a low self-discharge rate and a high recovery factor in a nonaqueous electrolyte secondary battery provided with a positive electrode coated with a positive electrode mix containing a positive electrode active material on a positive electrode current collector, a negative electrode coated with a negative electrode mix containing a negative electrode active material on a negative electrode current collector, and a nonaqueous electrolyte, particularly a lithium ion nonaqueous electrolyte secondary battery.

SOLUTION: This nonaqueous electrolyte secondary battery is provided with a positive electrode 2 coated with a positive electrode mix containing a positive electrode active material on a positive electrode current collector 11, a negative electrode 1 coated with a negative electrode mix containing a negative electrode active material on a negative electrode current collector 10, and a nonaqueous electrolyte.

Grains having the specific surface area of 0.20-0.32m²/g and the moisture value of 150ppm or below are used for the positive electrode active material.



LEGAL STATUS

[Date of request for examination]
[Date of sending the examiner's decision of rejection]
[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]
[Date of final disposal for application]
[Patent number]
[Date of registration]

[Number of appeal against examiner's decision
of rejection]

[Date of requesting appeal against examiner's
decision of rejection]

[Date of extinction of right]

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